

DATASHEET

4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL817-G Series



Features:

- Halogens free.
 (Br < 900ppm, Cl < 900ppm, Br+Cl < 1500ppm)
- Current transfer ratio
 (CTR: 50~600% at IF = 5mA, VCE = 5V)
- High isolation voltage between input and output (Viso = 5000Vrms)
- Creepage distance > 7.62mm
- Operating temperature up to +110°C
- Compact small outline package
- Compliance with EU REACH.
- •The product itself will remain within RoHS compliant version
- UL and cUL approved(No.E214129)
- VDE approved (No.132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

Description

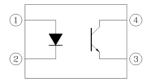
The EL817-G series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

Schematic



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector



Absolute Maximum Ratings (Ta=25°C)

| | Parameter | Symbol | Rating | Unit |
|--------------|--|------------------|------------|-------|
| | Forward current | I _F | 60 | mA |
| | Peak forward current (1us, pulse) | I _{FP} | 1 | Α |
| Input | Reverse voltage | V _R | 6 | V |
| | Power dissipation | D | 100 | mW |
| | Derating factor (above T _a = 100°C) | P_{D} | 2.9 | mW/°C |
| | Power dissipation | P _C - | 150 | mW |
| | Derating factor (above $T_a = 100^{\circ}C$) | | 5.8 | mW/°C |
| Output | Collector current | I _C | 50 | mA |
| | Collector-Emitter voltage | V _{CEO} | 80 | V |
| | Emitter-Collector voltage | V_{ECO} | 7 | V |
| Total Power | Dissipation | P _{TOT} | 200 | mW |
| Isolation Vo | ltage*1 | V_{ISO} | 5000 | V rms |
| Operating Te | emperature | T_{OPR} | -55 to 110 | °C |
| Storage Ten | nperature | T _{STG} | -55 to 125 | °C |
| Soldering Te | emperature*2 | T _{SOL} | 260 | °C |

Notes:

^{*1} AC for 1 minute, R.H.= $40 \sim 60\%$ R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

^{*2} For 10 seconds



Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Condition |
|-------------------|-----------------|------|------|------|------|-------------------|
| Forward Voltage | V_{F} | - | 1.2 | 1.4 | V | $I_F = 20mA$ |
| Reverse Current | I _R | - | - | 10 | μA | $V_R = 4V$ |
| Input capacitance | C _{in} | - | 30 | 250 | pF | V = 0, $f = 1kHz$ |

Output

| Parameter | Symbol | Min | Тур. | Max. | Unit | Condition | |
|------------------------|------------|-----|------|------|------|------------------------------|--|
| Collector-Emitter dark | lana | _ | - | 100 | nA | $V_{CE} = 20V$, $I_F = 0mA$ | |
| current | ICEO | _ | | | | | |
| Collector-Emitter | BV_CEO | 80 | _ | _ | V | $I_{\rm C} = 0.1 \rm mA$ | |
| breakdown voltage | PACEO | 00 | | | | IC = 0. IIIIA | |
| Emitter-Collector | D\/ | 7 | _ | _ | V | $I_E = 0.1 \text{mA}$ | |
| breakdown voltage | BV_{ECO} | 1 | - | - | V | | |

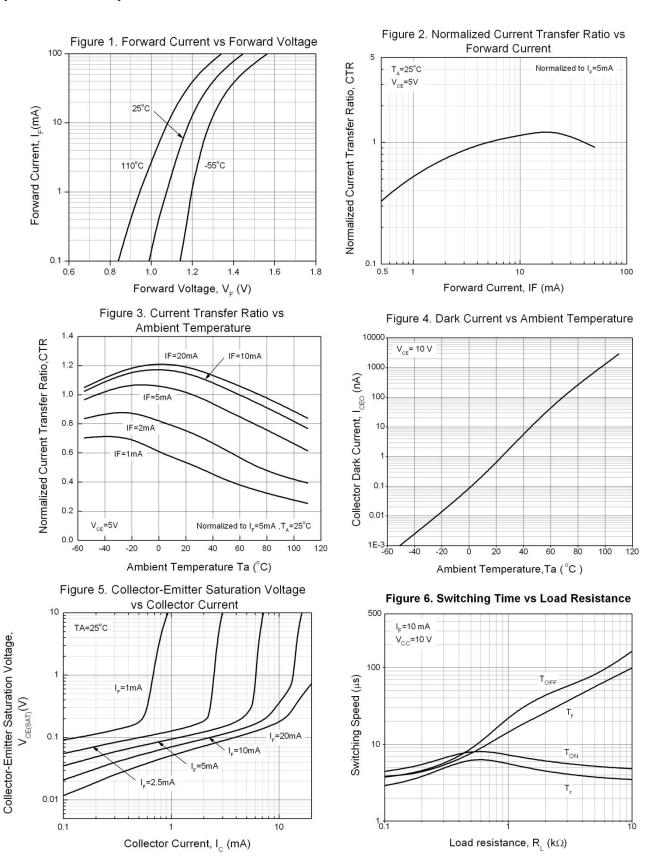
Transfer Characteristics

| Parameter | | Symbol | Min | Тур. | Max. | Unit | Condition |
|----------------------|--------------------------------------|-----------------|--------------------|------|------|---------------|---|
| | EL817 | | 50 | - | 600 | | I _F = 5mA ,V _{CE} = 5V |
| | EL817A | | 80 | - | 160 | | |
| Current | EL817B | CTR | 130 | - | 260 | - _ % - | |
| Transfer | EL817C | | 200 | - | 400 | | |
| ratio | EL817D | | 300 | - | 600 | | |
| | EL817X | | 100 | - | 200 | | |
| | EL817Y | | 150 | - | 300 | | |
| | Collector-Emitter saturation voltage | | - | 0.1 | 0.2 | V | $I_F = 20 \text{mA}, I_C = 1 \text{mA}$ |
| Isolation resistance | | R _{IO} | 5×10 ¹⁰ | - | - | Ω | V _{IO} = 500Vdc, 40~60% R.H. |
| Floating cap | Floating capacitance | | - | 0.6 | 1.0 | pF | $V_{IO} = 0$, $f = 1MHz$ |
| Cut-off freq | Cut-off frequency | | - | 80 | - | kHz | $V_{CE} = 5V$, $I_{C} = 2mA$ $R_{L} = 100\Omega$, $-3dB$ |
| Rise time | Rise time | | - | 6 | 18 | μs | $V_{CE} = 2V, I_{C} = 2mA,$ |
| Fall time | | t _f | - | 8 | 18 | μs | $R_L = 100\Omega$ |

^{*} Typical values at T_a = 25°C



Typical Electro-Optical Characteristics Curves





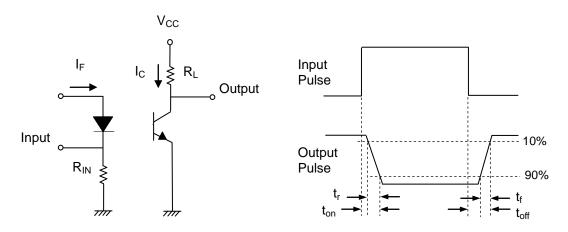


Figure 7. Switching Time Test Circuit & Waveforms



Order Information

Part Number

EL817X(Y)(Z)-FVG

Note

X = Lead form option (S, S1, S2, M or none)

Y = CTR Rank (A, B, C, D, X, Y or none)

Z = Tape and reel option (TU, TD or none)

F = Lead frame option (F: Iron, None: copper)

V = VDE safety (optional)

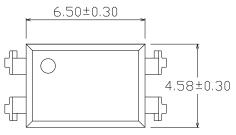
G = Halogens free

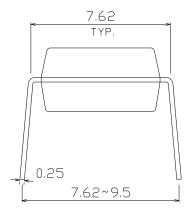
| Option | Description | Packing quantity |
|---------|---|---------------------|
| None | Standard DIP-4 | 100 units per tube |
| М | Wide lead bend (0.4 inch spacing) | 100 units per tube |
| S (TU) | Surface mount lead form + TU tape & reel option | 1500 units per reel |
| S (TD) | Surface mount lead form + TD tape & reel option | 1500 units per reel |
| S1 (TU) | Surface mount lead form (low profile) + TU tape & reel option | 1500 units per reel |
| S1 (TD) | Surface mount lead form (low profile) + TD tape & reel option | 1500 units per reel |
| S2 (TU) | Surface mount lead form (low profile) + TU tape & reel option | 2000 units per reel |
| S2 (TD) | Surface mount lead form (low profile) + TD tape & reel option | 2000 units per reel |

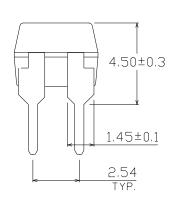


Package Dimension (Dimensions in mm)

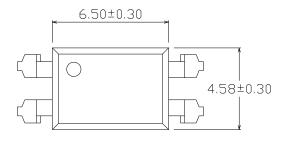
Standard DIP Type

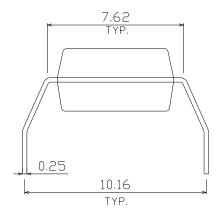


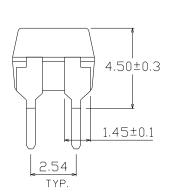




Option M Type

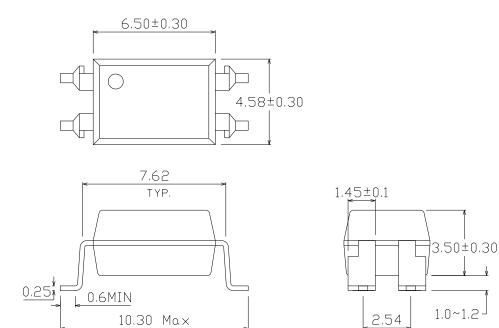




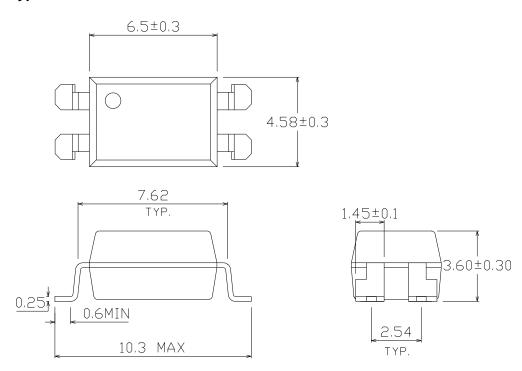




Option S Type

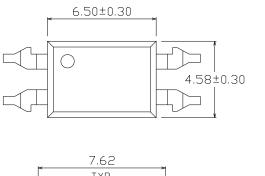


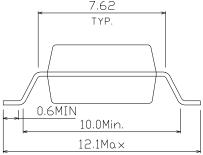
Option S1 Type

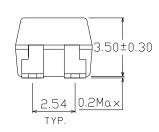




Option S2 Type

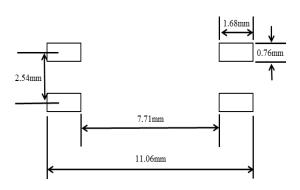




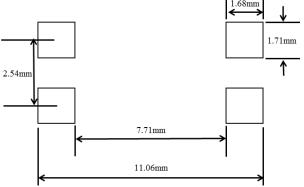


Recommended pad layout for surface mount leadform

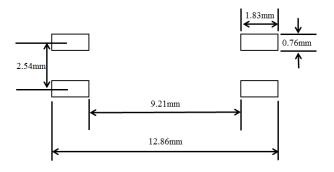
For S option



For S1 option



For S2 option



Notes

Suggested pad dimension is just for reference only.

Please modify the pad dimension based on individual need.



Device Marking



Notes

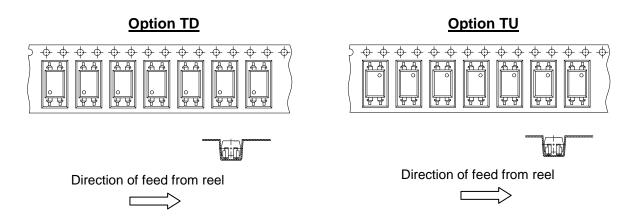
| EL | denotes EVERLIGHT |
|-----|-----------------------|
| 817 | denotes Device Number |

F denotes Factory Code (G: China and Green part) R denotes CTR Rank (A, B, C, D, X, Y or none)

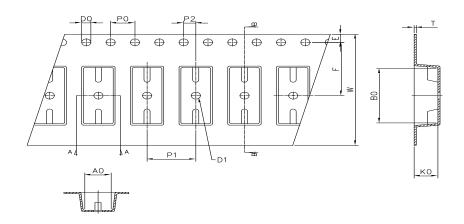
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE (optional)



Tape & Reel Packing Specifications



Tape dimensions



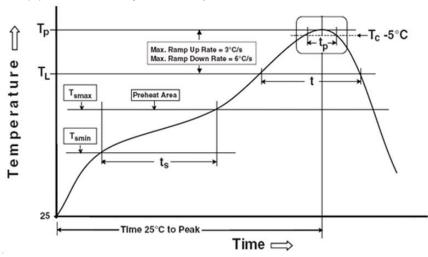
| Dimension No. | Ao | Во | Do | D1 | E | F |
|------------------------|----------|-----------|----------|----------|-----------|----------|
| Dimension (mm) S.S1 | 4.90±0.1 | 10.40±0.1 | 1.5±0.1 | 1.50±0.1 | 1.75±0.1 | 7.50±0.1 |
| Dimension (mm) S2 | 4.88±0.1 | 12.55±0.1 | 1.5±0.1 | 1.50±0.1 | 1.75±0.1 | 11.5±0.1 |
| Dimension No. | Ро | P1 | P2 | t | W | Ko |
| | | | | | | |
| Dimension (mm) S.S1 | 4.00±0.1 | 8.00±0.1 | 2.00±0.1 | 0.40±0.1 | 16.00±0.3 | 4.60±0.1 |



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin}) 150 °C Temperature max (T_{smax}) 200 °C

Time $(T_{smin} \text{ to } T_{smax})$ (t_s) 60-120 seconds Average ramp-up rate $(T_{smax} \text{ to } T_p)$ 3 °C/second max

Other

Liquidus Temperature (T_L) 217 °C

Time above Liquidus Temperature (t_L) 60-100 sec

Peak Temperature (T_P) 260°C Time within 5 °C of Actual Peak Temperature: T_P - 5°C 30 s

Ramp- Down Rate from Peak Temperature 6°C /second max.

Time 25°C to peak temperature 8 minutes max.

Reflow times 3 times



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